CERTIFICATE OF MAILING

I hereby certify that this correspondence is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner of Patents and 13/96 Trademarks, Washington, D.C. 20231, on 2/13/96

Docket: 0756-1299

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

The re PATENT application of Hongyong ZHANG et al.
Serial No. 08/462,742

ial No. 08/462,742) Group Art Unit: 1104 led: June 5, 1995) Examiner Radomsky

ed: June 5, 1995
: SEMICONDUCTOR DEVICE AND

FABRICATION METHOD OF THE
)

SAME) Date: February 13, 1996

Honorable Commissioner of Patents and Trademarks Washington, D.C. 20231

RECEASION MAD 4 4 1 1

Sir:

Transmitted herewith is an amendment in the above-identified () application.

- [X] No additional fee is required.
- [X] A check in the amount of \$110.00 to cover the one month petition for extension of time fee is enclosed.
- [X] In the event applicant(s) has overlooked the need for any petition and fee for extension of time, and such extension is required, applicant(s) requests that this be considered a petition therefor and that such fee be charged to Deposit Account No. 19-2380.
- [X] The Commissioner is hereby authorized to charge fees under 37 CFR 1.16, 1.17, 1.20(a), 1.20(b), 1.20(c) and 1.20 (d) (except the Issue Fee) which may be required now or hereafter, or credit any overpayment, to Deposit Account No. 19-2380. A duplicate copy of this sheet is attached.

Respectfully submitted,

Bradley D. Blanche

Reg. No. 38,387

Sixbey, Friedman, Leedom & Ferguson, P.C. 2010 Corporate Ridge, Suite 600

McLean, Virginia 22102

(703) 790-9110

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- 1 -

Docket: 0756-1299 M. ROS

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re PATENT application of)

Hongyong ZHANG et al.

Serial No. 08/462,742) Art Unit: 1104

Filed: June 5, 1995) Examiner: L. Radomsky

For: SEMICONDUCTOR DEVICE AND)

FABRICATION METHOD OF THE)

SAME) Date: February 1

MAR 4.

AMENDMENT

Honorable Commissioner of Patents and Trademarks

Washington, D.C. 20231

Sir:

In response to the Official Action mailed October 13, 1995, please amend the above-identified application as follows:

In the Claims:

Please amend claims 3, 4, 14, 15, 18, 20, 22, 23, 24 and 25 as follows:

3. (Amended) A method for fabricating a semiconductor device comprising:

forming a substantially amorphous silicon film on a substrate;